

Combined Analysis: Probing the crystallite sizes by XRD down to nm, together with structure, texture, phases, residual stresses, complemented by XRF, GiXRF and electron diffraction

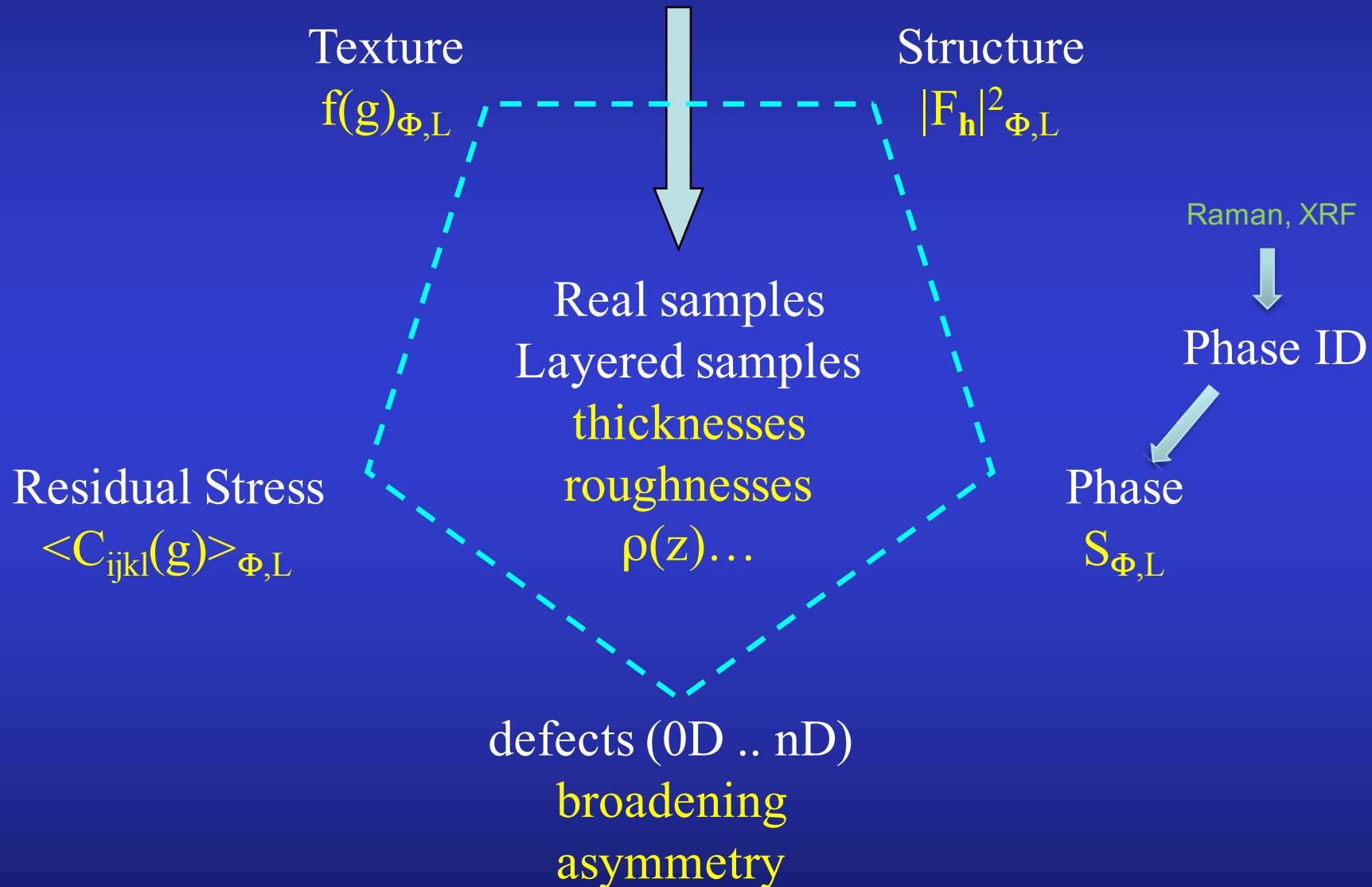
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Normandie Université

Nanoday, Caen, 8th Feb. 2018

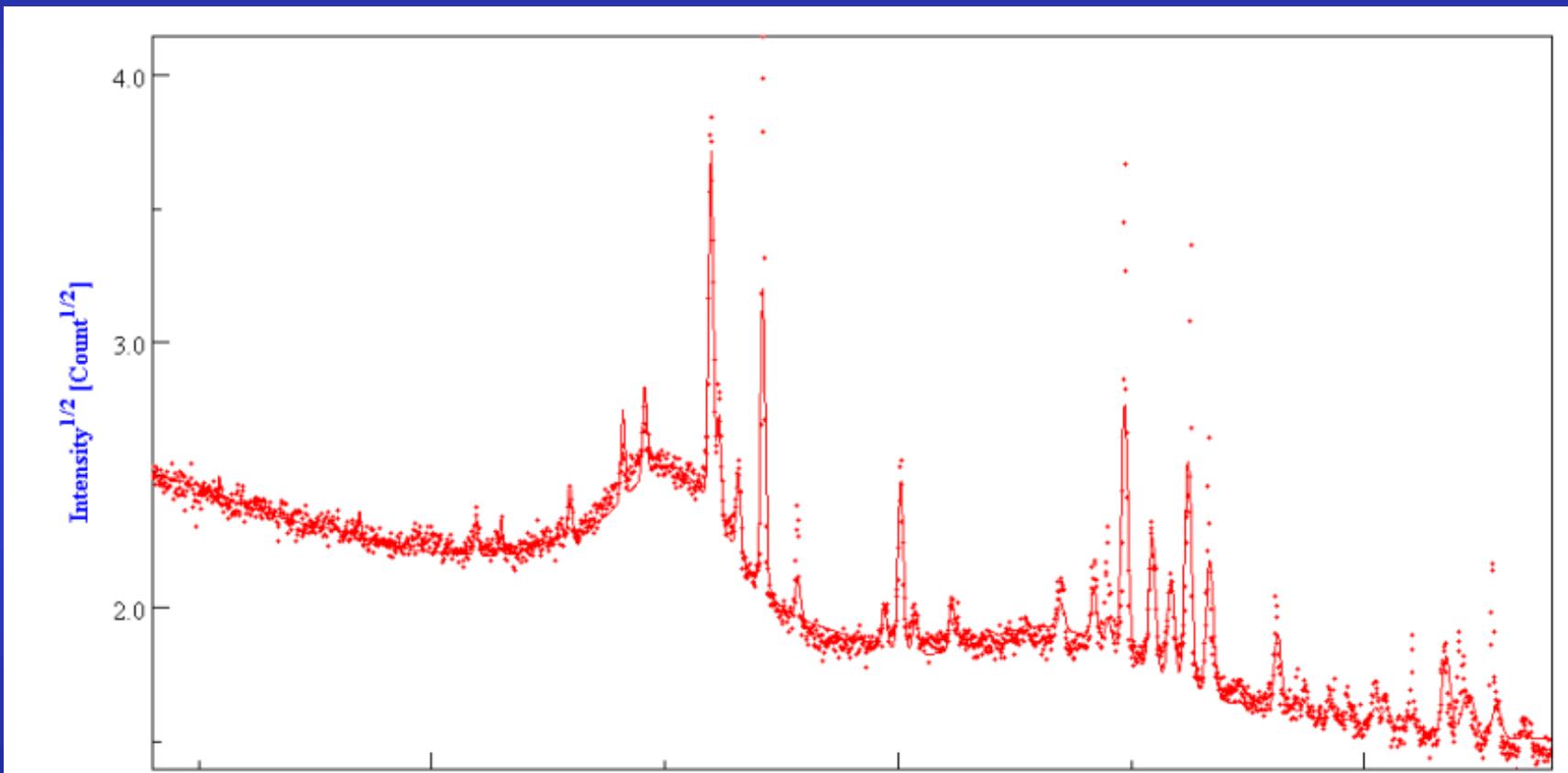
X-ray scattering “sees”



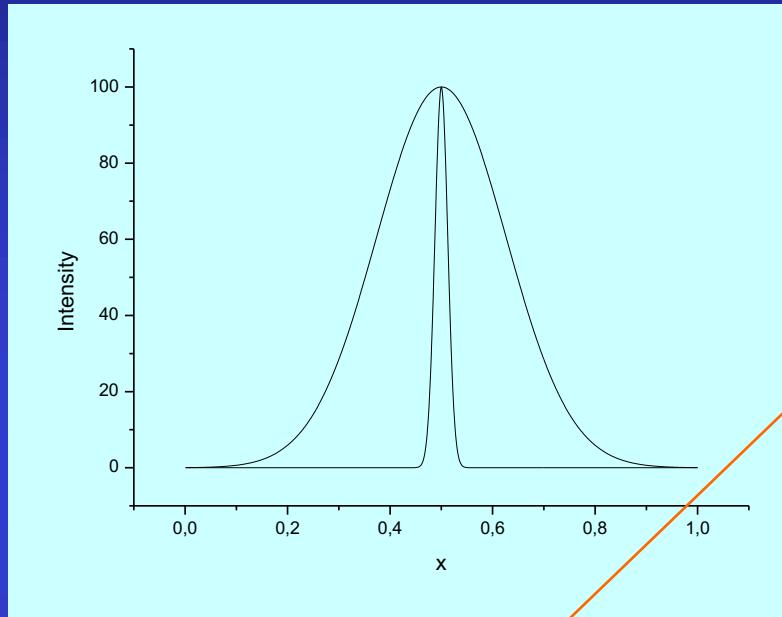
Nanosizes: Line Broadening

- Instrumental broadening
- Finite size of the crystals
 - acts like a Fourier truncation: size broadening
- Imperfection of the periodicity
 - due to d_h variations inside crystals: microstrain effect
- Generally: 0D, 1D, 2D, 3D defects
- All quantities are average values over the probed volume
 - electrons, x-rays, neutrons: complementary distributions: mean values depend on distributions' shapes

Irradiated Fluorapatites



Instrumental broadening



$$g(x) = g_\lambda(x) \otimes g_g(x)$$

Energy dispersion

Geometrical aberrations

$$h(x) = f(x) \otimes g(x) + b(x) = b(x) + \int_{-\infty}^{+\infty} f(y)g(x-y)dy$$

Measured profile

Sample contribution

Background

Rietveld: extended to lots of spectra

$$y_c(y_S, \theta, \eta) = y_b(y_S, \theta, \eta) + I_0 \sum_{i=1}^{N_L} \sum_{\Phi=1}^{N_\Phi} \frac{v_{i\Phi}}{V_{c\Phi}^2} \sum_h L_p(\theta) j_{\Phi h} |F_{\Phi h}|^2 \Omega_{\Phi h}(y_S, \theta, \eta) P_{\Phi h}(y_S, \theta, \eta) A_{i\Phi}(y_S, \theta, \eta)$$

Texture:

$$P_h(y_S) = \int_{\tilde{\varphi}} f(g, \tilde{\varphi}) d\tilde{\varphi}$$

E-WIMV, components ...

Strain-Stress:

$$\langle S \rangle_{geo}^{-1} = \left[\prod_{m=1}^N S_m^{v_m} \right]^{-1} = \prod_{m=1}^N S_m^{-v_m} = \prod_{m=1}^N (S_m^{-1})^{v_m} = \langle S^{-1} \rangle_{geo} = \langle C \rangle_{geo}$$

Geometric mean, Voigt, Reuss, Hill ...

Layering:

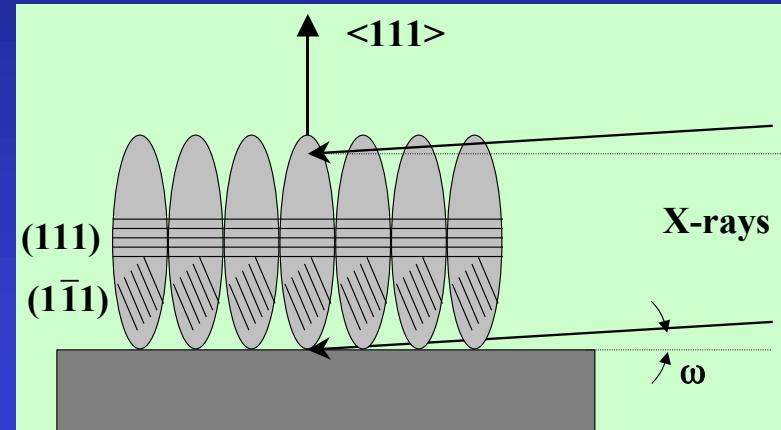
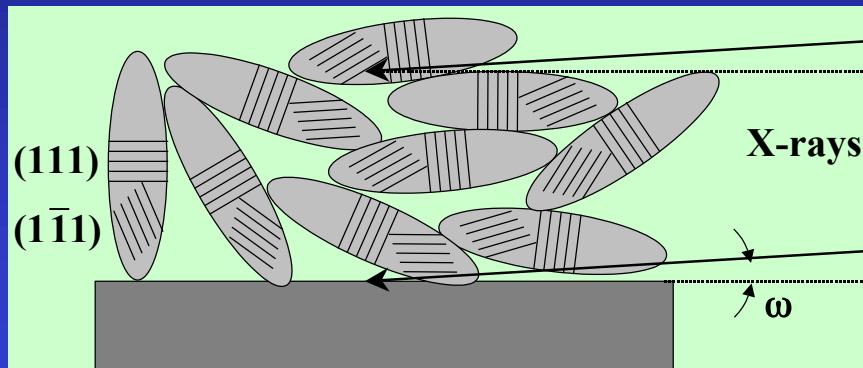
$$C_\chi^{\text{top film}} = g_1 (1 - \exp(-\mu T g_2 / \cos \chi)) / (1 - \exp(-2\mu T / \sin \omega \cos \chi))$$

XRR: Parrat, DWBA, EDP ...

XRF, PDF, Raman ...

Popa Line Broadening model

Crystallite sizes, shapes, μ strains, distributions



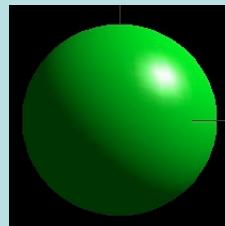
- Texture helps the "real" mean shape determination

$$\langle \mathbf{R}_{\vec{h}} \rangle = \sum_{\ell=0}^L \sum_{m=0}^{\ell} R_{\ell}^m K_{\ell}^m(\chi, \varphi)$$

Symmetrised spherical harmonics

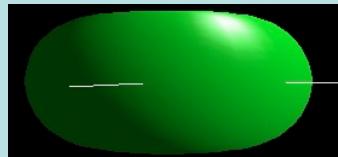
$$K_{\ell}^m(\chi, \varphi) = P_{\ell}^m(\cos \chi) \cos(m\varphi) + P_{\ell}^m(\cos \chi) \sin(m\varphi)$$

$$\begin{aligned}
 \langle \mathbf{R}_h \rangle &= R_0 + R_1 P_2^0(x) + R_2 P_2^1(x) \cos \varphi + R_3 P_2^1(x) \sin \varphi + R_4 P_2^2(x) \cos 2\varphi + R_5 P_2^2(x) \sin 2\varphi + \\
 \langle \varepsilon_h^2 \rangle E_h^4 &= E_1 h^4 + E_2 k^4 + E_3 \ell^4 + 2E_4 h^2 k^2 + 2E_5 \ell^2 k^2 + 2E_6 h^2 \ell^2 + 4E_7 h^3 k + 4E_8 h^3 \ell + 4E_9 k^3 h + \\
 &\quad 4E_{10} k^3 \ell + 4E_{11} \ell^3 h + 4E_{12} \ell^3 k + 4E_{13} h^2 k \ell + 4E_{14} k^2 h \ell + 4E_{15} \ell^2 k h
 \end{aligned}$$

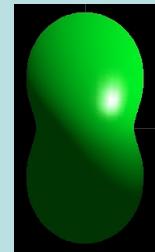


$\bar{1}$

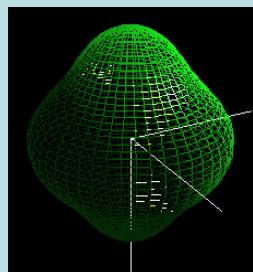
R_0



$R_0, R_1 < 0$



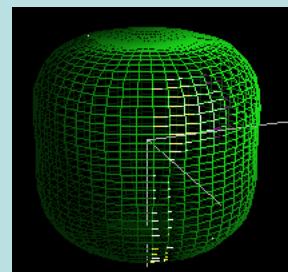
$R_0, R_1 > 0$



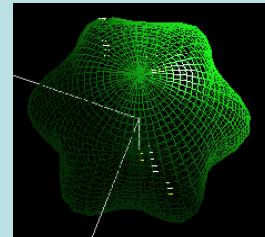
$R_0, R_6 > 0$



$R_0,$
 R_2 and $R_6 > 0$

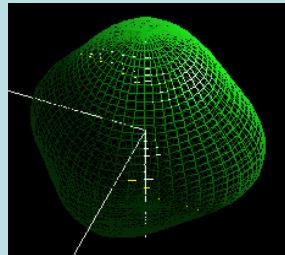


$R_0, R_6 < 0$

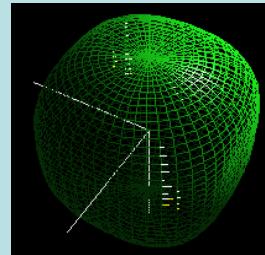


$6/m$

$R_0, R_4 > 0$



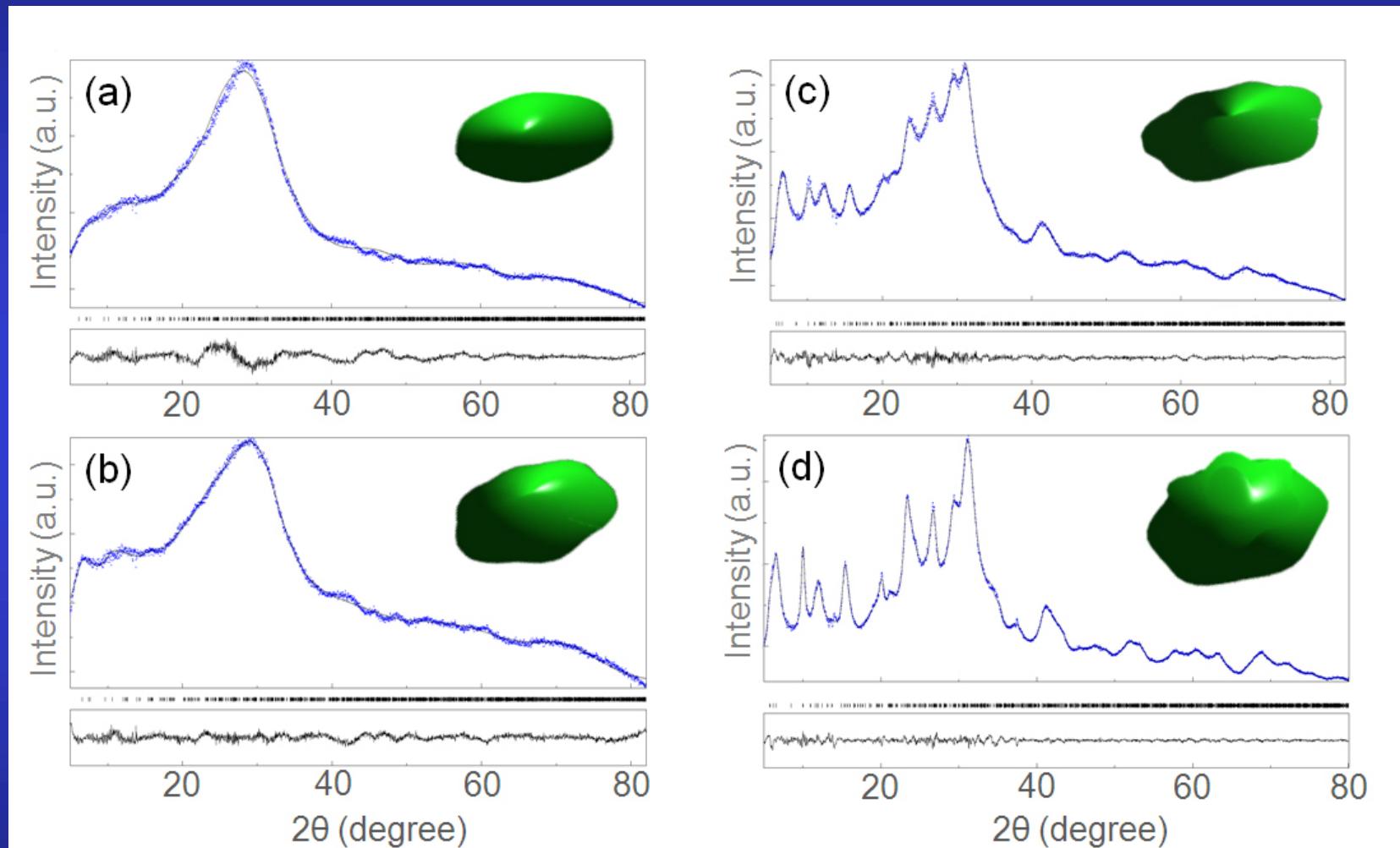
$R_0, R_1 > 0$



$m3m$

$R_0, R_1 < 0$

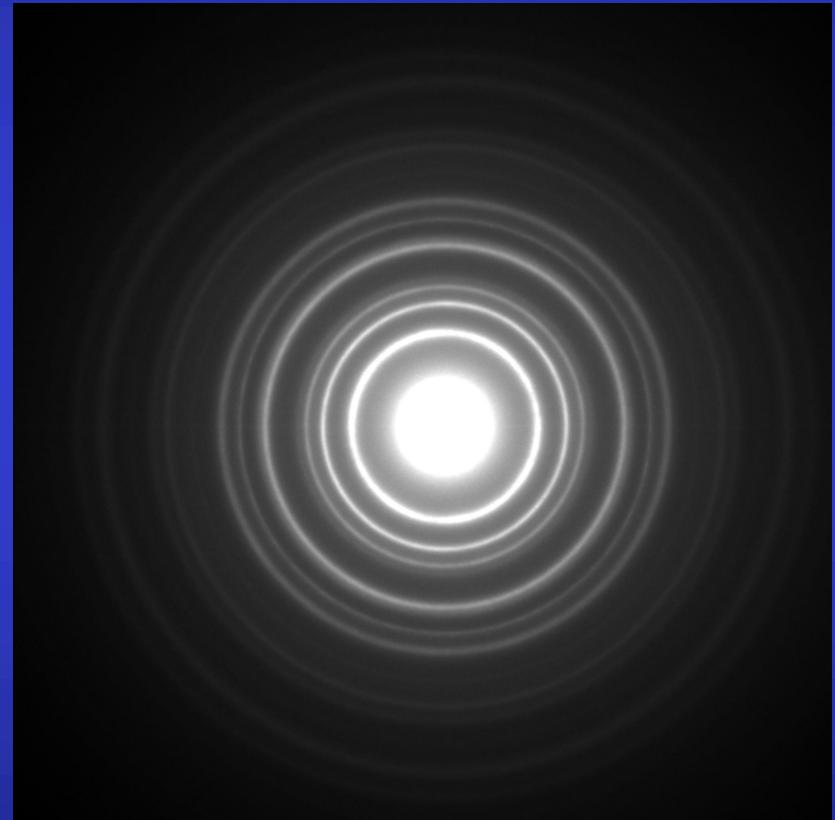
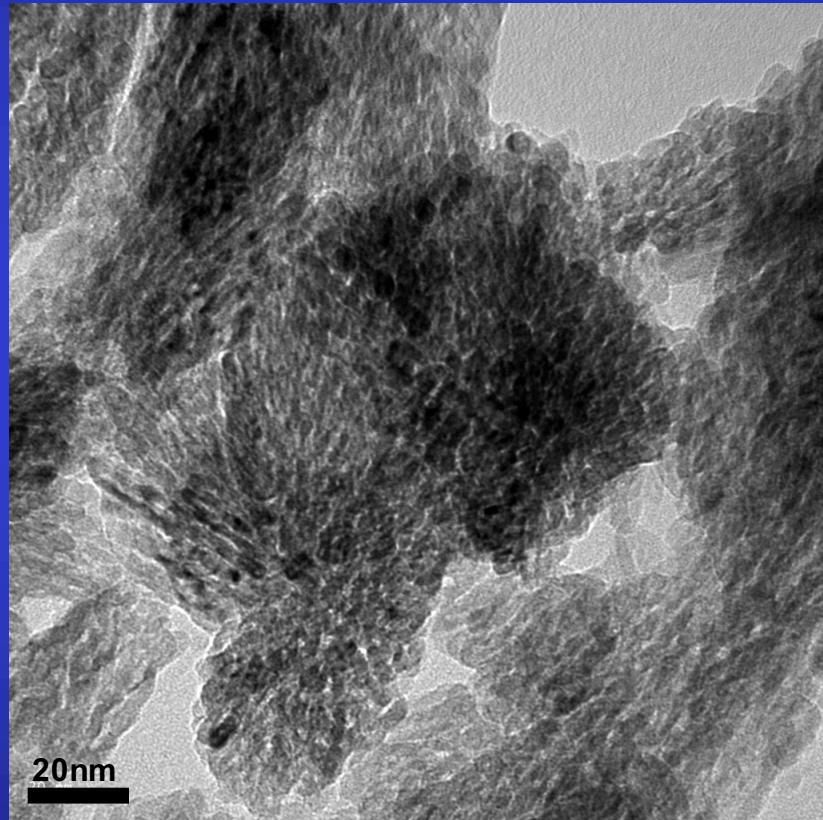
EMT nanocrystalline zeolite



Ng, Chateigner, Valtchev, Mintova: *Science* **335** (2012) 70

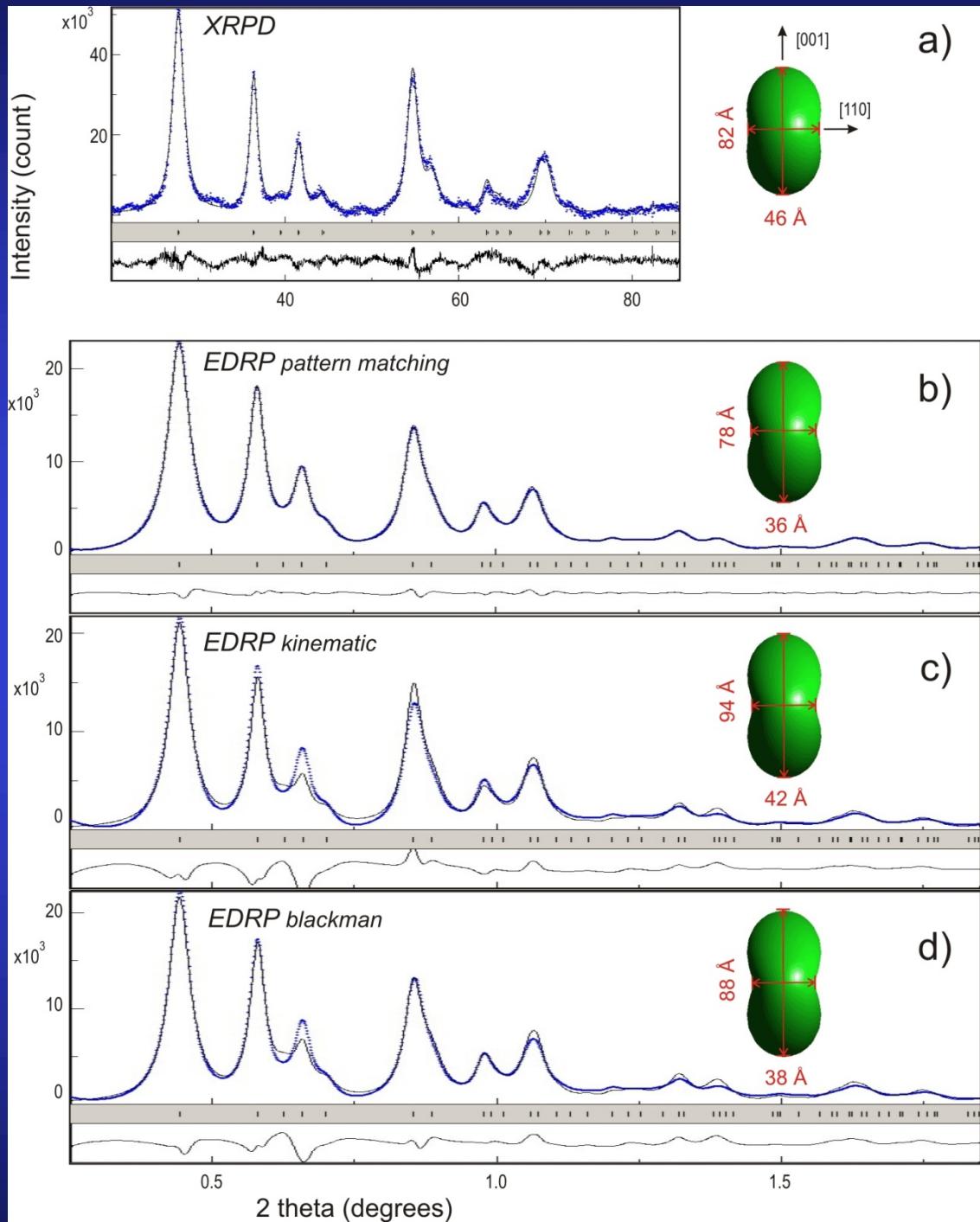
Microstructure of nanocrystalline materials: TiO₂ rutile

- quantitative analysis of electron diffraction ring pattern ?

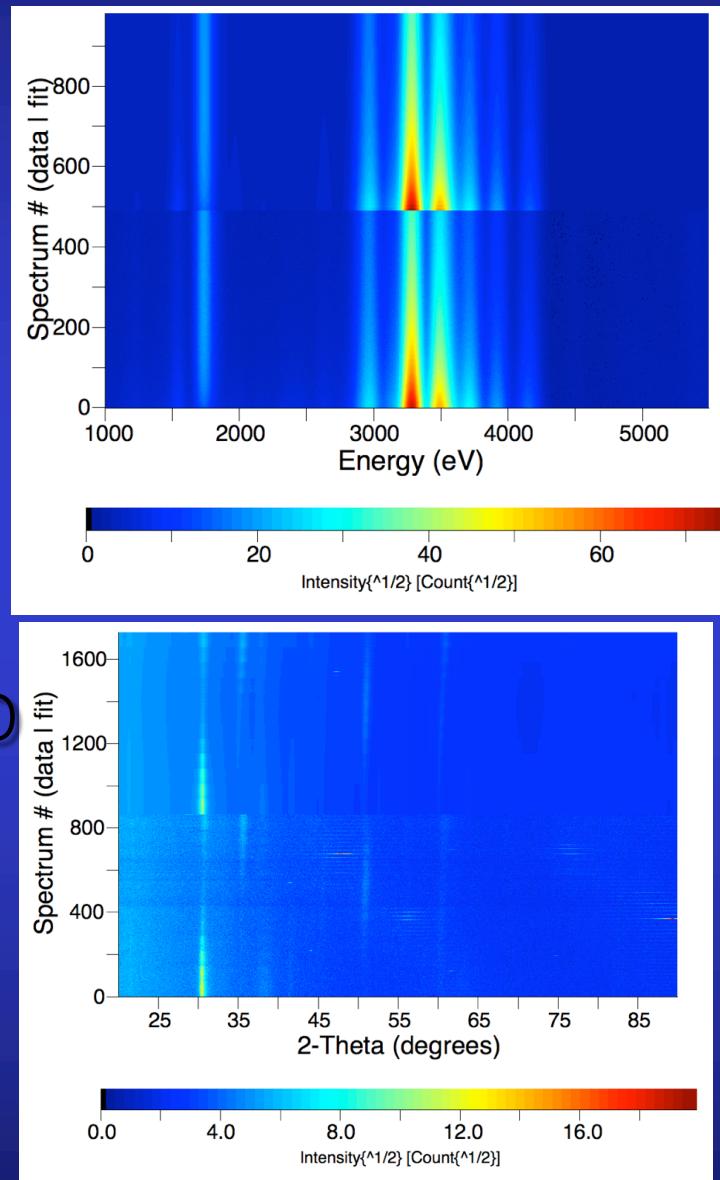
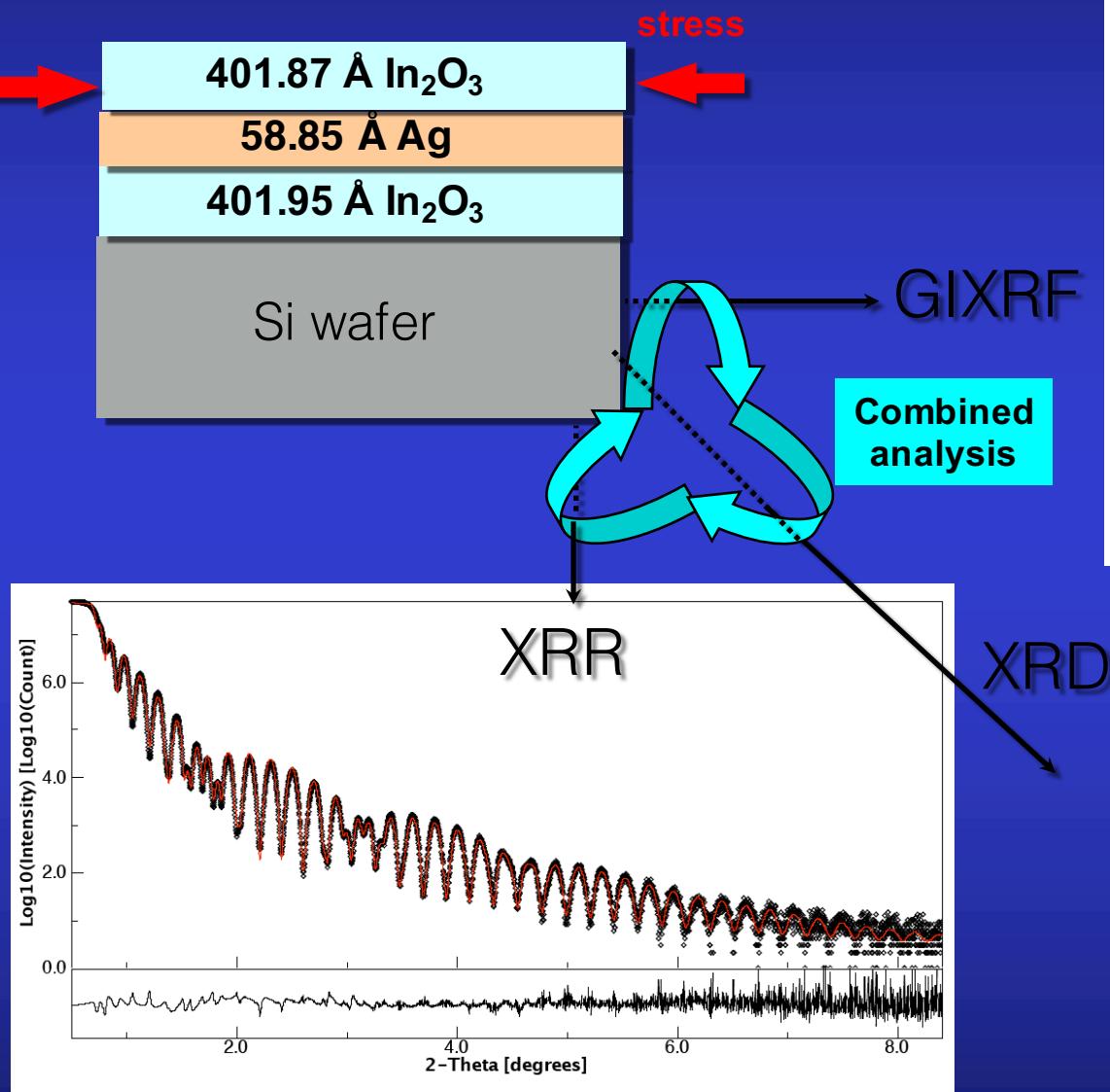


FEI Tecnai G2 (300kV) with an Ultrascan 1000 (2048x2048 14μm pixels)

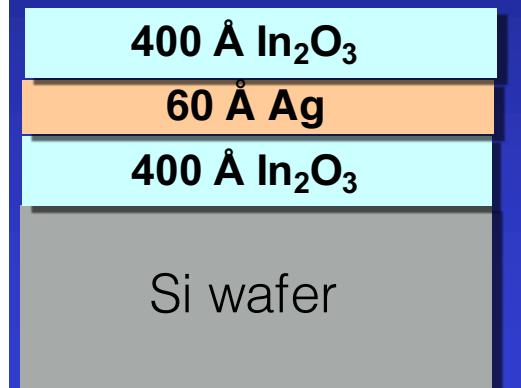
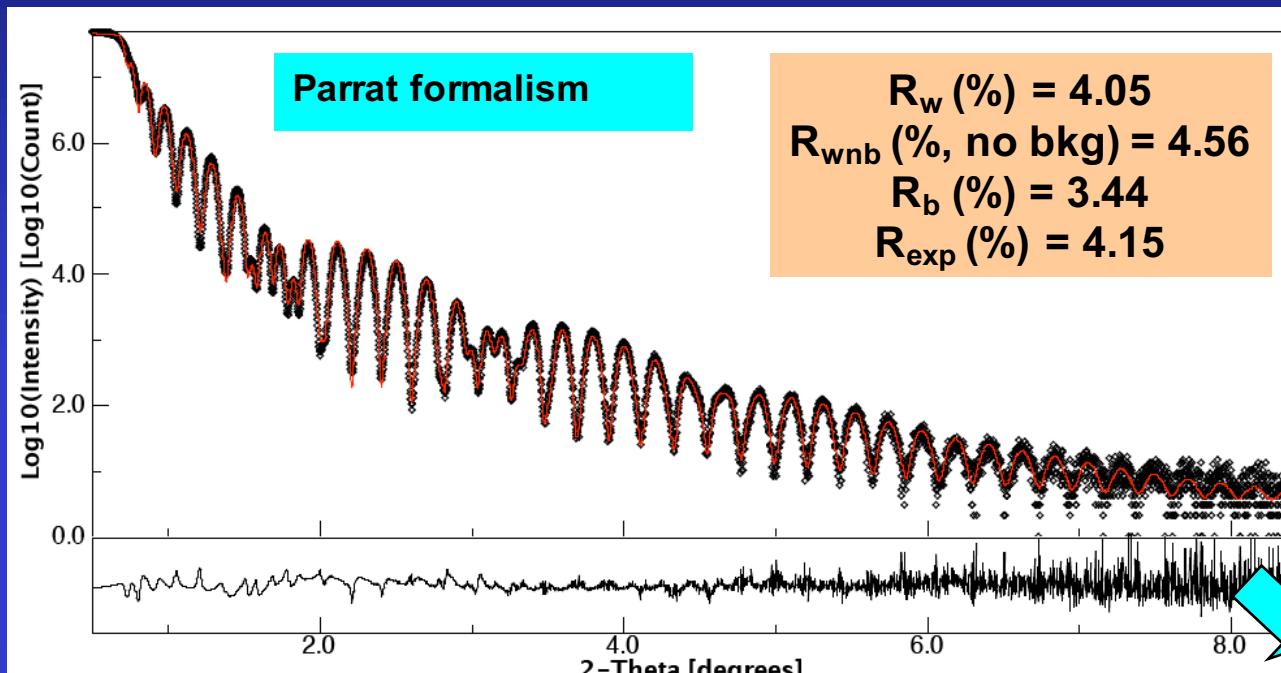
Popa $R_0 + R_1$



Combined XRR, XRD & GIXRF Analysis



XRR



17.9 Å In_2O_3 porous

384.9 Å In_2O_3

57.4 Å Ag

403.1 Å In_2O_3

Si wafer

Top layer: $q_c = 0.0294 \text{ \AA}^{-1}$; roughness $r = 0.38 \text{ nm}$

Top In_2O_3 : $q_c = 0.0504 \text{ \AA}^{-1}$; $r = 2.06 \text{ nm}$

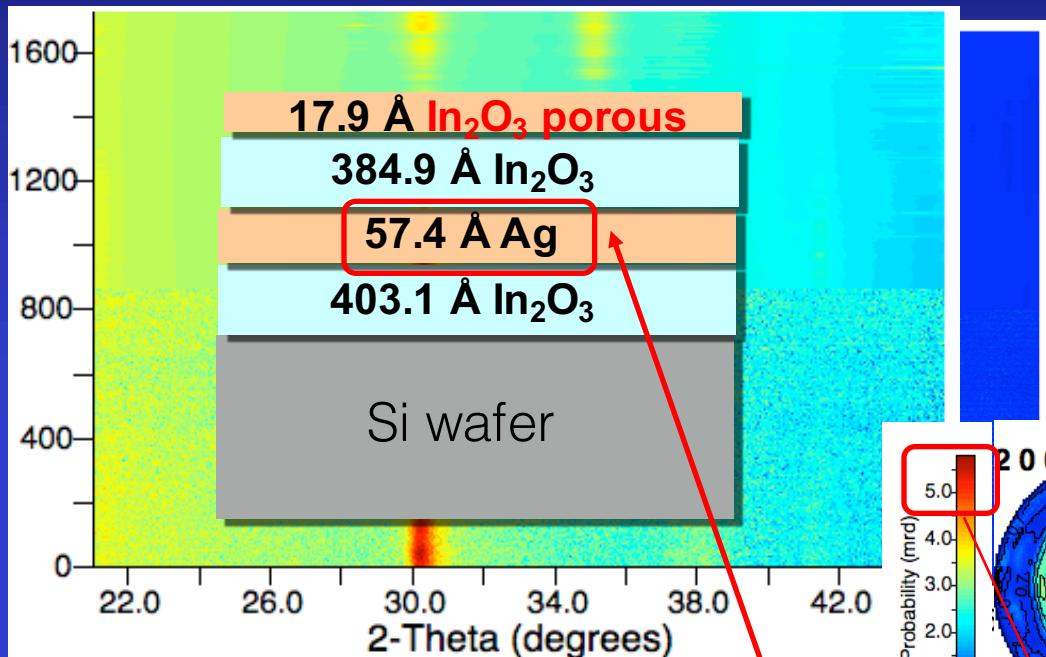
Ag: $q_c = 0.0576 \text{ \AA}^{-1}$; $r = 0.26 \text{ nm}$

Bottom In_2O_3 : $q_c = 0.04889 \text{ \AA}^{-1}$; $r = 6.74 \text{ nm}$

Si wafer: $q_c = 0.0313 \text{ \AA}^{-1}$; $r = 0.73 \text{ nm}$

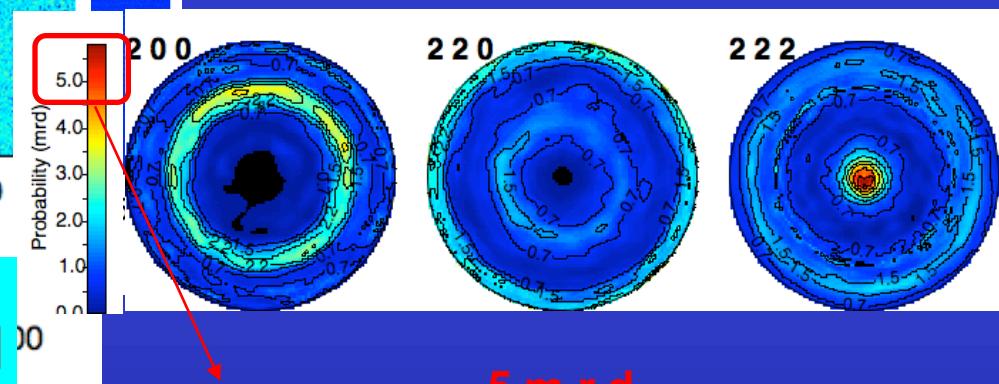
Highly porous In_2O_3 layer

XRD



R_w (%) = 23.97
 R_{wnb} (%), no bkg) = 58.31
 R_b (%) = 18.71
 R_{exp} (%) = 22.04

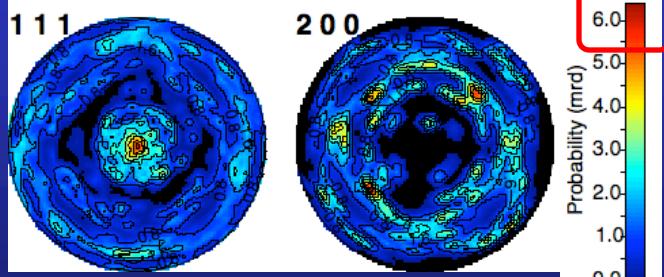
In_2O_3



Refined Ag phase parameters

- ↳ Isotropic crystallite size = 56.4 (1.3) Å
- ↳ Cell parameter: $a = 4.0943(7)$ Å

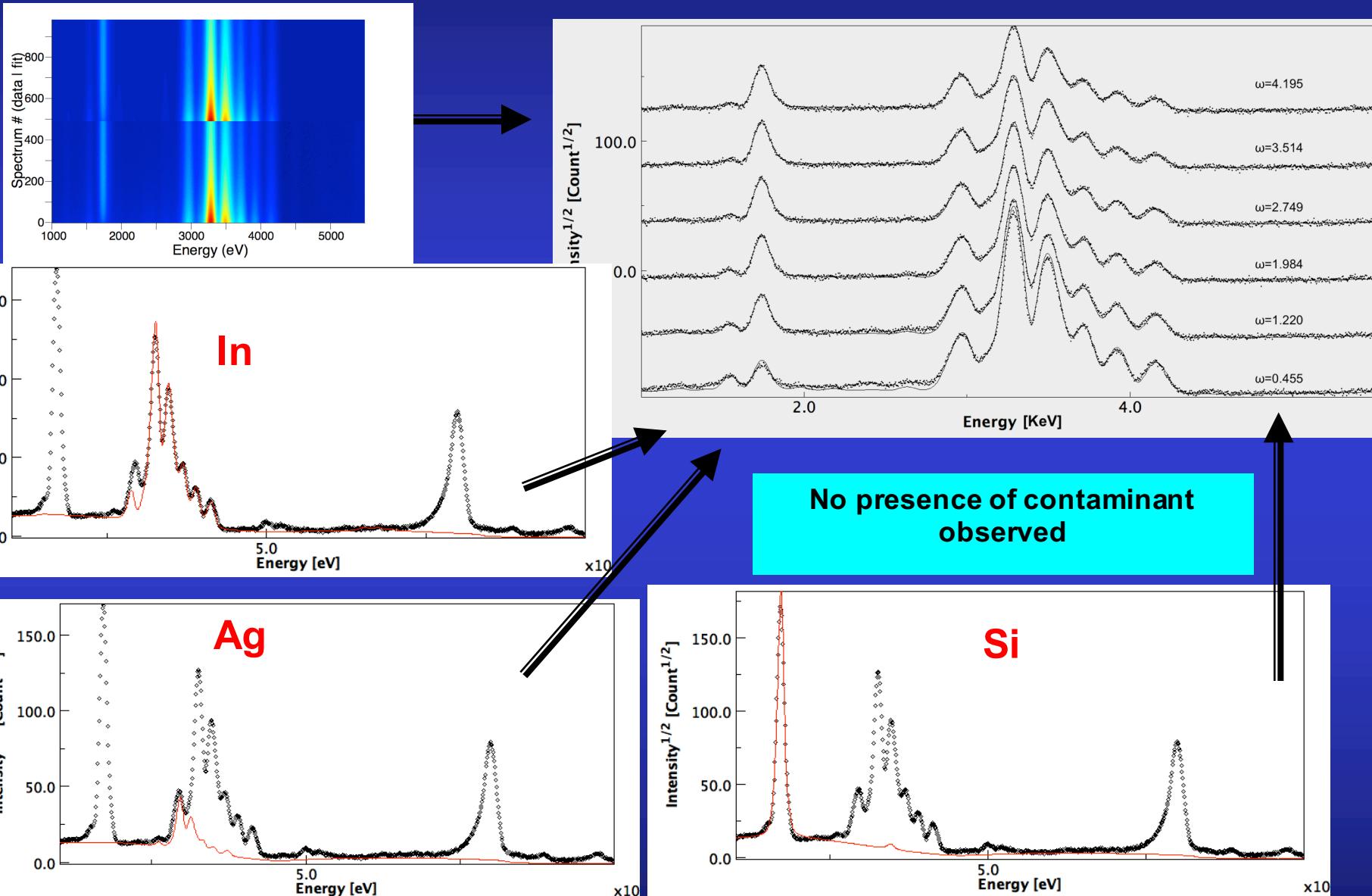
Ag:



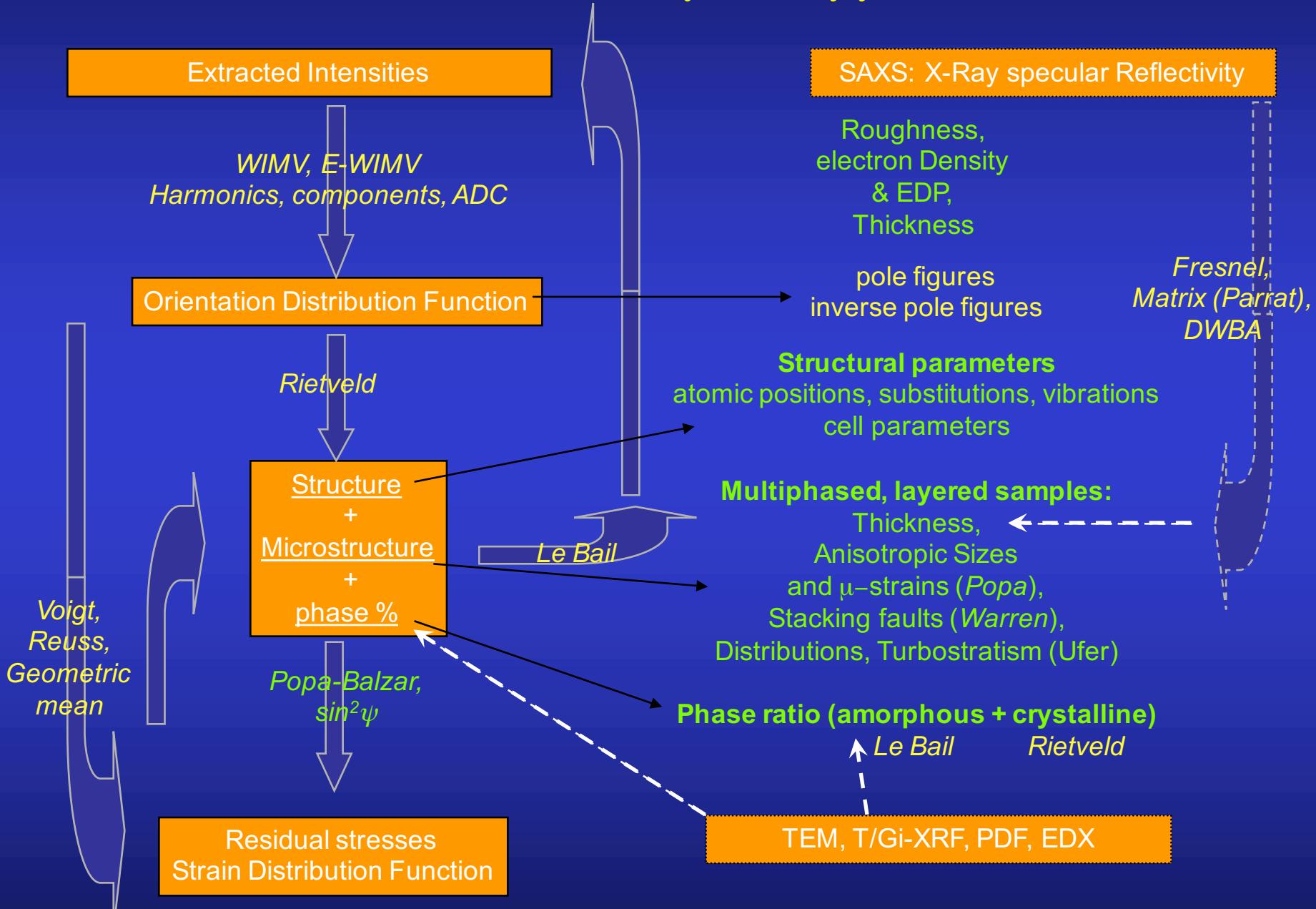
Refined In_2O_3 phase parameters

- ↳ $\sigma_{xx} = -1$ GPa (in-plane compressive stress)
- ↳ Isotropic crystallite size = 153.2(5) Å
- ↳ Cell parameter: $a = 10.2104(5)$ Å

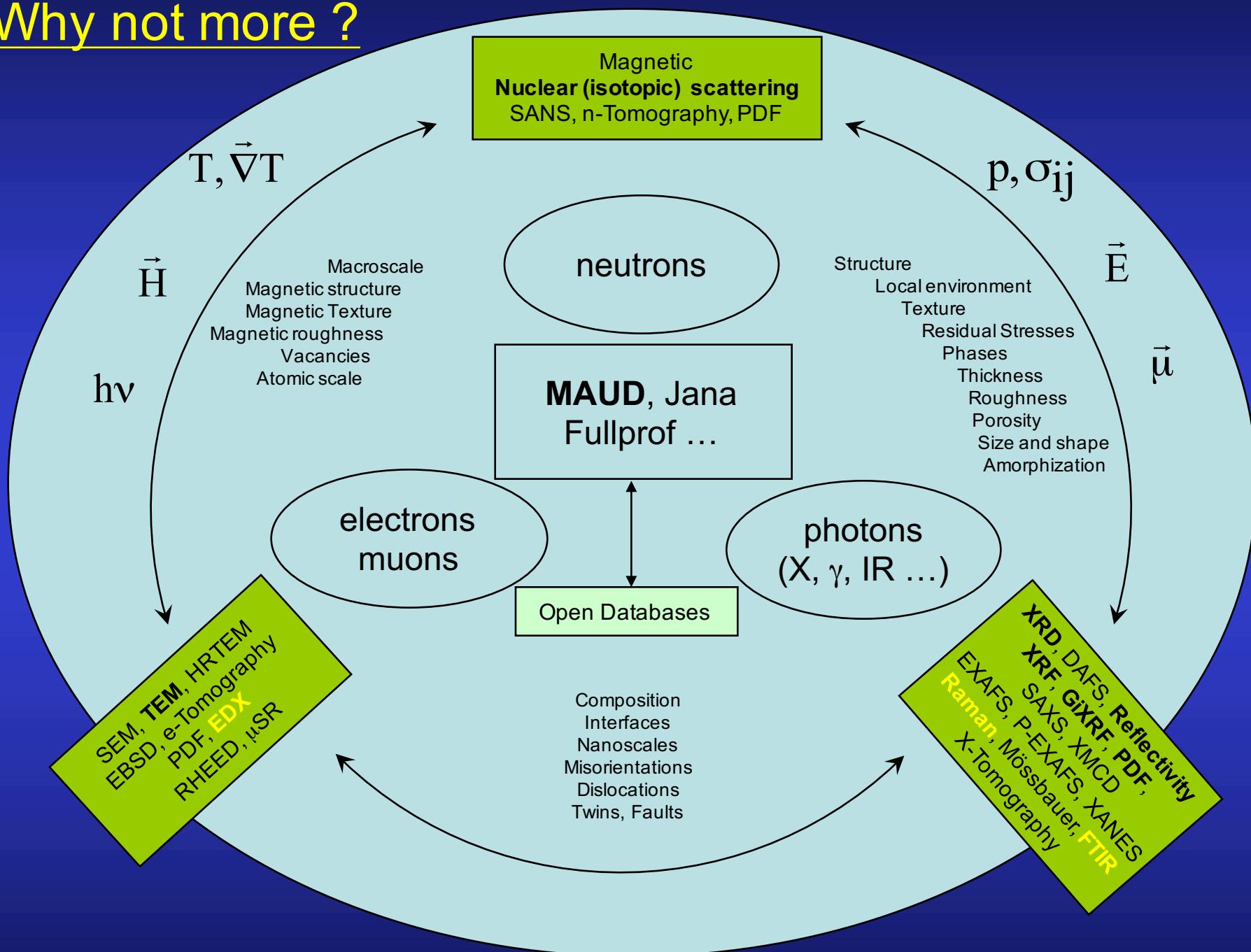
GixRF

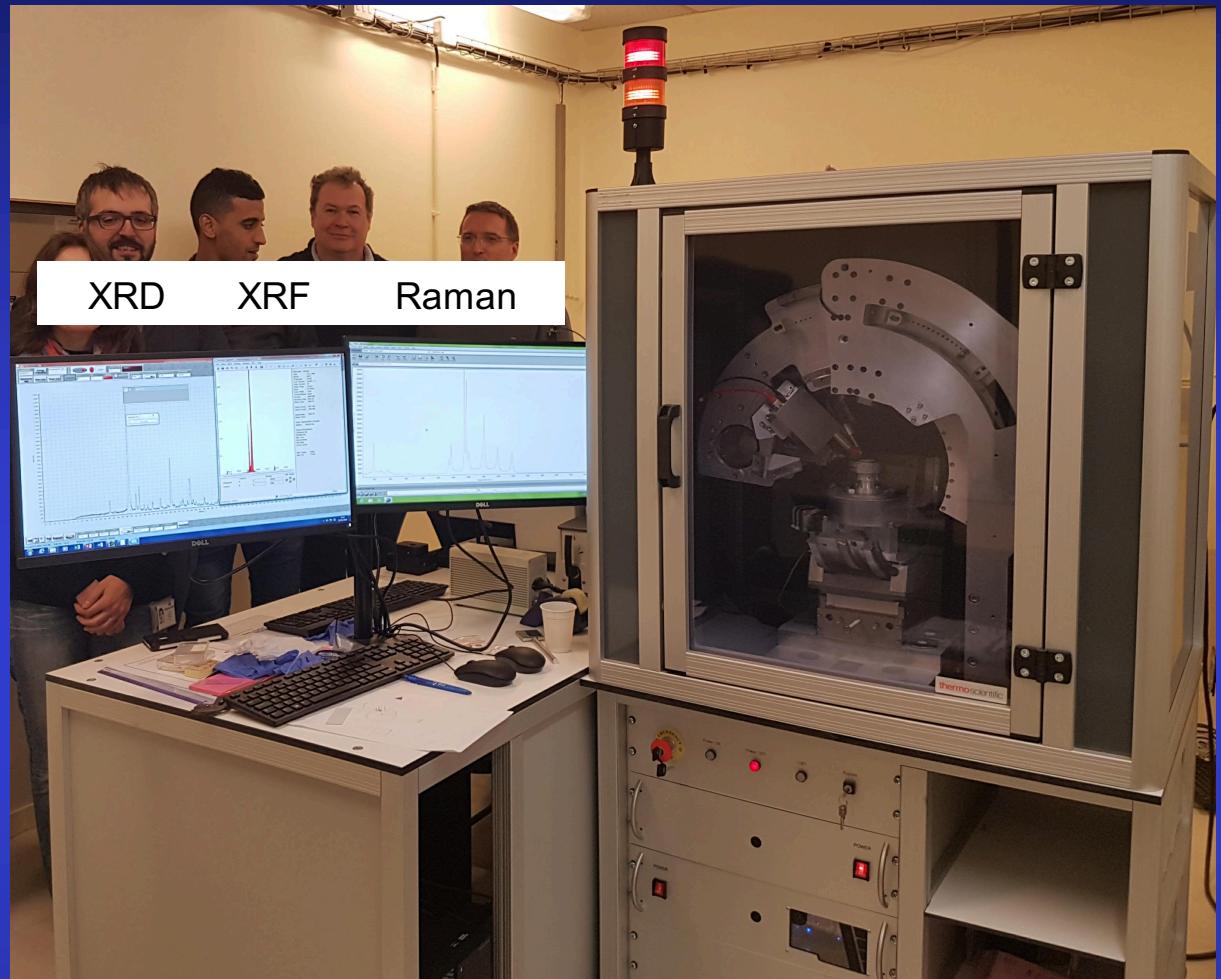


Combined Analysis approach



Why not more ?





Thanks !

Combined Analysis Workshop in Caen:
4th - 8th July 2018 !

www.ecole.ensicaen.fr/~chateign/formation/